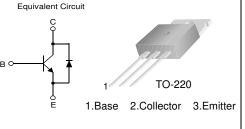
FAIRCHILD

SEMICONDUCTOR

KSC5302D

High Voltage High Speed Power Switch Application

- High Breakdown Voltage : BV_{CBO}=800V
 Built-in Free-wheeling Diode makes efficient anti saturation operation
 Suitable for half bridge light ballast Applications
- · No need to interest an hFE value because of low variable storage-time
- spread
- Even though corner spirit product
- Low base drive requirement



KSC5302D

NPN Silicon Transistor

Absolute Maximum Ratings T_C=25°C unless otherwise noted

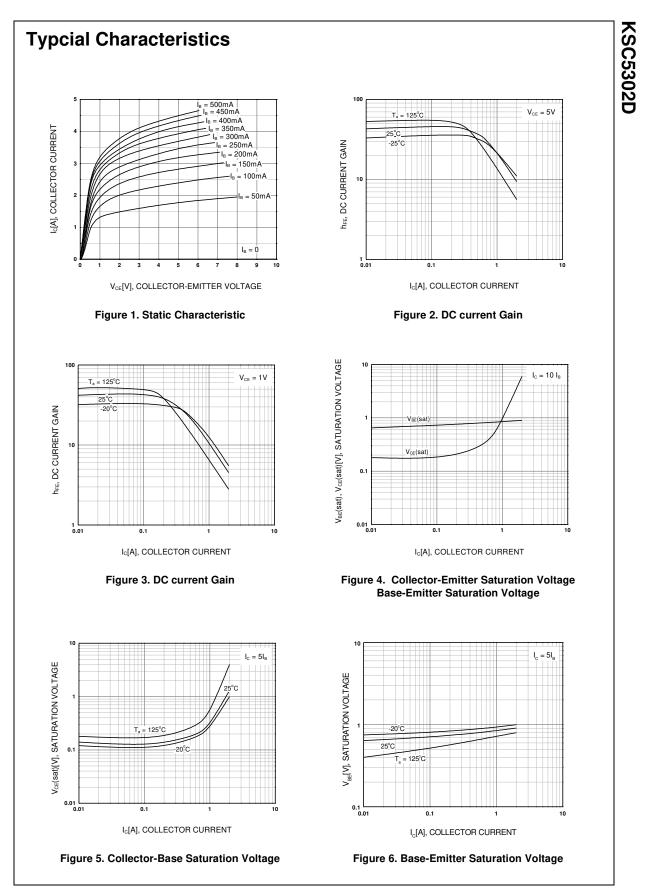
Symbol	Parameter	Value	Units V V V A	
V _{CBO}	Collector-Base Voltage	800		
√ _{CEO}	Collector-Emitter Voltage	400		
V _{EBO}	Emitter-Base Voltage	12		
I _C	Collector Current (DC)	2		
I _{CP}	*Collector Current (Pulse)	5	A A A	
I _B	Base Current (DC)	1		
BP	*Base Current (Pulse)	2		
Power Dissipation(T _C =25°C)		50	W	
ТJ	Junction Temperature	150	°C	
Т _{STG}	Storage Temperature	- 55 ~ 150	°C	

Thermal Characteristics $T_{C}=25^{\circ}C$ unless otherwise noted

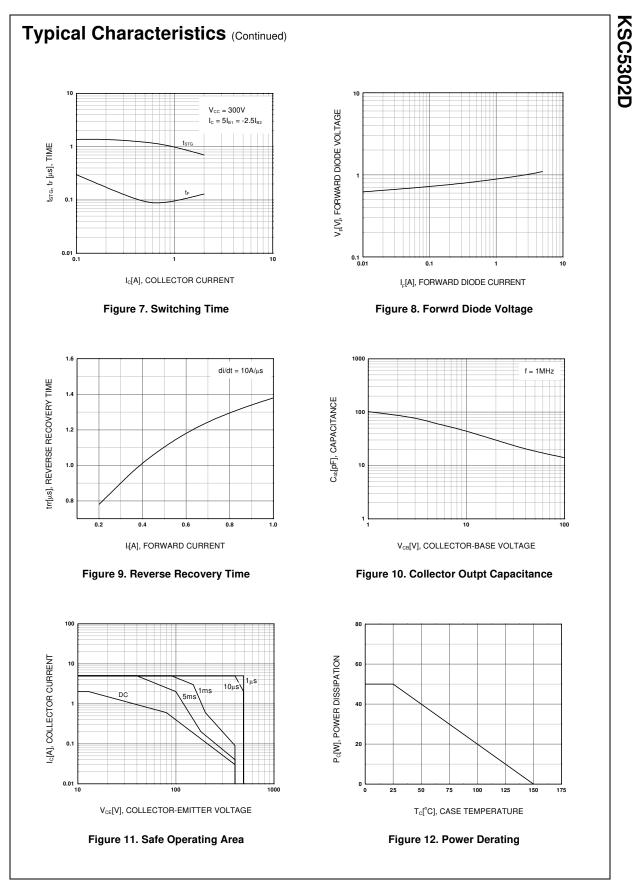
Symbol	Char	Rating	Unit	
R _{θjc}	Thermal Resistance	Junction to Case	2.5	°C/W
$R_{\theta ja}$		Junction to Ambient	62.5	

Symbol	Parameter	Test Condition	Min.	Тур.	Max.	Units
3V _{CBO}	Collector-Base Breakdown Voltage	I _C =1mA, I _E =0	800	-	-	V
BV _{CEO}	Collector-Emitter Breakdown Voltage	I _C =5mA, I _B =0	400	-	-	V
BV _{EBO}	Emitter Cut-off Current	I _E =1mA, I _C =0	12	-	-	V
I _{CBO}	Collector Cut-off Current	V _{CB} =500V, I _E =0	-	-	10	μA
I _{EBO}	Emitter Cut-off Current	$V_{EB} = 9V, I_{C} = 0$	-	-	10	μA
h _{FE1} h _{FE2}	DC Current Gain	V _{CE} =1V, I _C =0.4A V _{CE} =1V, I _C =1A	20 10	-	-	
V _{CE} (sat)	Collector-Emitter Saturation Voltage	I _C =0.4A, I _B =0.04A I _C =1A, I _B =0.2A		-	0.4 0.5	V V
V _{BE} (sat)	Base-Emitter Saturation Voltage	I _C =0.4A, I _B =0.04A I _C =1A, I _B =0.2A	-	-	0.9 1.0	V V
C _{ob}	Output Capacitance	V _{CB} = 10V, f=1MHz	-	-	75	pF
ON	Turn ON time	V _{CC} =300V, I _C =1A	-	-	150	ns
İstg	Storage Time	l _{B1} = 0.2A, l _{B2} =-0.5A,	-	-	2	μs
F	Fall Time	$R_L = 300\Omega$	-	-	0.2	μs
t _{STG}	Storage Time	V _{CC} =15V, V _Z =300V	-	-	2.35	μs
t _F	Fall Time	I _C = 0.8A, I _{B1} = 0.16A I _{B2} = -0.16A , L = 200μH	-	-	150	ns
V _F	Diode Forward Voltage	I _F = 0.4A I _F = 1A	-	-	1.2 1.5	V V
t _{rr}	*Reverse Recovery Time (di/dt = 10A/μs)	I _F = 0.2A I _F = 0.4A	-	800 1	-	ns μs
		$I_F = 1A$	-	1.4	-	μs

*Pulse Test : Pulse Width=5mS, Duty cycles \leq 10%

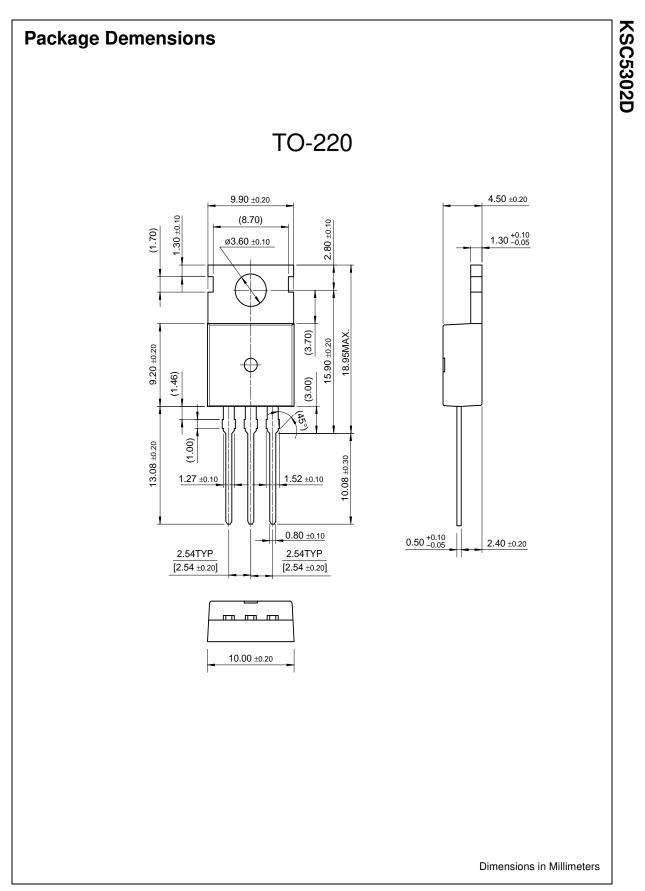


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Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
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Optoelectronics		[E-	Distributor and field sales
Markets and	• High Breakdown Voltage:		<u>representatives</u>
applications	BV _{CBO} =800V	This pagePrint version	Dotted line Quality and reliability
New products	Built-in Free-wheeling Diode makes	This page <u>r the version</u>	Dotted line
Product selection and	efficient anti saturation operation		Design tools
parametric search Cross-reference	 Suitable for half bridge light ballast applications 		
search	 No need to interest in h_{FE} value because 		1
<u>source</u>	of low variable storage-time spread	-	
technical information	• Even though corner spirit product		
buy products	Low base drive requirement		
technical support	- back to top		
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High Voltage High Speed Power Switch

back to top

Product status/pricing/packaging

Product	Product status	Pricing*	Package type	Leads	Packing method
KSC5302DTU	Full Production	\$0.467	TO-220	3	RAIL

* 1,000 piece Budgetary Pricing

back to top

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